# **Reset Circuit with Manual Reset**

#### Description

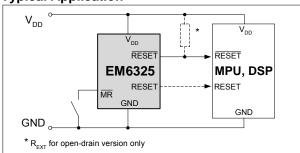
The EM6325 is an ultra-low current reset circuit available in a large variety of configurations and very small packages for maximum flexibility in all end-applications up to 125°C and using power supplies between 1.5V and 5.5V.

This circuit monitors the supply voltage of any electronic system, and generates the appropriate reset signal after a fixed reset timeout period. The threshold defines the minimum allowed voltage which guarantees the good functionality of the system. When  $V_{DD}$  rises above  $V_{TH}$ , the output remains active for an additional delay time. This allows the system to stabilize before getting fully active.

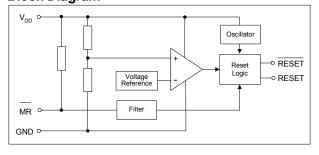
This circuit features a Manual Reset: an input that asserts reset when pulled low (MR with internal pull-up).

Small SC70-4L, SC70-5L and SOT23-5L packages as well as ultra-low supply current of 2.9µA make the EM6325 an ideal choice for portable and battery-operated devices.

#### **Typical Application**



#### **Block Diagram**



#### **Features**

- Manual reset function
- 200ms reset timeout period (1.6ms, 25ms, 1600ms on request)
- □ Ultra-low supply current of 2.9µA (V<sub>DD</sub>=3.3V)
- Operating temperature range: -40°C to +125°C
- ±1.5% reset threshold accuracy
- 11 reset threshold voltages V<sub>TH</sub>: 4.63V, 4.4V, 3.08V, 2.93V, 2.63V, 2.2V, 1.8V, 1.66V, 1.57V, 1.38V, 1.31V
- 3 reset output options:

Active-low RESET push-pull

Active-low RESET open-drain

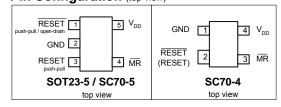
Active-high RESET push-pull

- ☐ Immune to short negative V<sub>DD</sub> transients
- ☐ Guaranteed Reset valid down to 0.9V
- ☐ Threshold hysteresis: 2.1% of V<sub>TH</sub>
- Very small SOT23-5L, SC70-5L and SC70-4L

#### **Applications**

- Computers
- Servers and workstations
- Modems
- Wireless communication
- Metering
- Playstations
- □ PDA, Webpad
- Automotive systems

### Pin Configuration (top view)



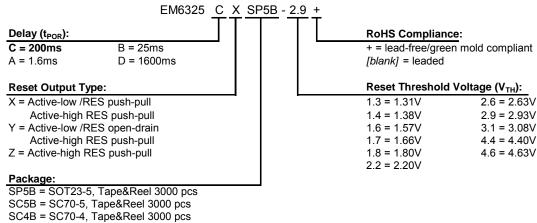
#### **Pin Description**

Pin						
SOT23-5L / SC70-5L	SC70-4L	Name	Function			
1	2	RESET	Active-low RESET output. RESET remains low for the reset timeout period and then goes high after all reset conditions are deasserted or after MR goes from low to high			
2	1	GND	Ground			
3	2	RESET	Active-high RESET output. RESET remains high for the reset timeout period and then goes low after all reset conditions are deasserted or after MR goes from low to high			
4	3	MR	Manual Reset input with an internal pull-up $15k\Omega$ resistor. Reset remains active as long as $\overline{MR}$ is low and for $t_{POR}$ after $\overline{MR}$ returns high. $\overline{MR}$ can be driven with a CMOS output or shorted to ground with a switch			
5	4	$V_{DD}$	Supply Voltage (5.5V max.)			

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#### **Ordering Information**



## **Top Marking**

Package top marking below is for most parts in leaded package (first letter is "A"). For lead-free/green mold (RoHS) parts, the first letter of top marking begins with letter "B" instead of letter "A". The underscore "\_\_" refers to the four-letter code for the package (eg. SP5B, SC4B, ...).

Part Number	Top Marking						
EM6325AX1.3	ANAA	EM6325BX1.3	ANBA	EM6325CX1.3	ANCA	EM6325DX1.3	ANDA
EM6325AX1.4	ANAB	EM6325BX1.4	ANBB	EM6325CX1.4	ANCB	EM6325DX1.4	ANDB
EM6325AX1.6	ANAC	EM6325BX1.6	ANBC	EM6325CX1.6	ANCC	EM6325DX1.6	ANDC
EM6325AX1.7	ANAD	EM6325BX1.7	ANBD	EM6325CX1.7	ANCD	EM6325DX1.7	ANDD
EM6325AX1.8	ANAE	EM6325BX1.8	ANBE	EM6325CX1.8	ANCE	EM6325DX1.8	ANDE
EM6325AX2.2	ANAF	EM6325BX2.2	ANBF	EM6325CX2.2	ANCF	EM6325DX2.2	ANDF
EM6325AX2.6	ANAG	EM6325BX2.6	ANBG	EM6325CX2.6	ANCG	EM6325DX2.6	ANDG
EM6325AX -2.9	ANAH	EM6325BX -2.9	ANBH	EM6325CX2.9	ANCH	EM6325DX -2.9	ANDH
EM6325AX -3.1	ANAJ	EM6325BX -3.1	ANBJ	EM6325CX -3.1	ANCJ	EM6325DX -3.1	ANDJ
EM6325AX -4.4	ANAK	EM6325BX -4.4	ANBK	EM6325CX -4.4	ANCK	EM6325DX -4.4	ANDK
EM6325AX -4.6	ANAL	EM6325BX -4.6	ANBL	EM6325CX -4.6	ANCL	EM6325DX -4.6	ANDL
EM6325AY1.3	ANAM	EM6325BY1.3	ANBM	EM6325CY1.3	ANCM	EM6325DY1.3	ANDM
EM6325AY1.4	ANAN	EM6325BY1.4	ANBN	EM6325CY1.4	ANCN	EM6325DY1.4	ANDN
EM6325AY1.6	ANAP	EM6325BY1.6	ANBP	EM6325CY1.6	ANCP	EM6325DY1.6	ANDP
EM6325AY1.7	ANAQ	EM6325BY1.7	ANBQ	EM6325CY1.7	ANCQ	EM6325DY1.7	ANDQ
EM6325AY1.8	ANAR	EM6325BY1.8	ANBR	EM6325CY1.8	ANCR	EM6325DY1.8	ANDR
EM6325AY2.2	ANAS	EM6325BY -2.2	ANBS	EM6325CY2.2	ANCS	EM6325DY -2.2	ANDS
EM6325AY2.6	ANAT	EM6325BY2.6	ANBT	EM6325CY2.6	ANCT	EM6325DY2.6	ANDT
EM6325AY2.9	ANAU	EM6325BY2.9	ANBU	EM6325CY2.9	ANCU	EM6325DY2.9	ANDU
EM6325AY3.1	ANAV	EM6325BY3.1	ANBV	EM6325CY3.1	ANCV	EM6325DY3.1	ANDV
EM6325AY4.4	ANAW	EM6325BY4.4	ANBW	EM6325CY4.4	ANCW	EM6325DY4.4	ANDW
EM6325AY4.6	ANAX	EM6325BY -4.6	ANBX	EM6325CY4.6	ANCX	EM6325DY -4.6	ANDX

#### Standard Versions, Samples

Sample stock is generally held on **standard versions** (below) only. Non standard versions have a 30,000 pieces minimum order quantity. Please contact factory for other versions not shown here and for availability of non standard versions.

EM6325AXSC4B-2.9
EM6325CXSC5B-2.9
EM6325CXSP5B-1.3
EM6325CXSP5B-2.6
EM6325CXSP5B-2.9
EM6325CXSP5B-3.1
EM6325CYSP5B-2.9
EM6325CYSP5B-4.6
EM6325DXSC4B-2.6
EM6325CXSP5B-4.6



**Absolute Maximum Ratings** 

Parameter	Symbol	Conditions
Voltage at V <sub>DD</sub> to GND	$V_{DD}$	-0.3V to +6V
Minimum voltage at any signal pin	$V_{MIN}$	GND - 0.3V
Maximum voltage at any signal pin	$V_{MAX}$	$V_{DD} + 0.3V$
Electrostatic discharge max. to MIL-STD-883C method 3015.7 with ref. to V <sub>SS</sub>	$V_{ESD}$	2000V
Max. soldering conditions	T <sub>MAX</sub>	250°C x 10s
Storage Temperature Range	T <sub>STG</sub>	-65°C to +150°C

Stresses above these listed maximum ratings may cause permanent damages to the device. Exposure beyond specified operating conditions may affect device reliability or cause malfunction.

### **Handling Procedures**

This device has built-in protection against high static voltages or electric fields; however, anti-static precautions must be taken as for any other CMOS component. Unless otherwise specified, proper operation can only occur when all terminal voltages are kept within the voltage range. Unused inputs must always be tied to a defined logic voltage level.

### **Operating Conditions**

Parameter	Symbol	Min	Max	Unit
Supply voltage	$V_{DD}$	0.9	5.5	V
Operating Temperature	T <sub>A</sub>	-40	+125	°C

### **Electrical Characteristics**

Unless otherwise specified:  $V_{DD}$ = 0.9V to 5.5V,  $T_A$ =-40°C to +125°C (note 1).

Parameter	Symbol	Con	ditions	Min	Тур	Max	Unit
		V <sub>DD</sub> =1.5V	+25°C	_	2.3	4.6	
Supply current (note 2)		V <sub>00</sub> -1.5V	-40°C to +125°C	-	2.5	7	
	I <sub>DD</sub>	V <sub>DD</sub> =3.3V	+25°C	-	2.9	5.5	μΑ
Supply current (note 2)	¹DD		-40°C to +125°C	-		8.3	μА
		V <sub>DD</sub> =5.0V	+25°C	_	3.4	6.3	
		V DD-3.0 V	-40°C to +125°C	-		9.6	
		EM6325 – 1.3	+25°C	1.290	1.31	1.330	
			-40°C to +85°C	1.245		1.382	
			-40°C to +125°C	1.221		1.387	
			+25°C	1.359		1.401	
		EM6325 - 1.4	-40°C to +85°C	1.311	1.38	1.456	
			-40°C to +125°C	1.286		1.461	
			+25°C	1.546		1.594	
		EM6325 - 1.6	-40°C to +85°C	1.492	1.57	1.656	
			-40°C to +125°C	1.463		1.663	
			+25°C	1.635		1.685	
		EM6325 - 1.7	-40°C to +85°C	1.577	1.66	1.751	
			-40°C to +125°C	1.547		1.758	
		+25°C 1.773 EM6325 – 1.8 -40°C to +85°C 1.710 -40°C to +125°C 1.678	+25°C	1.773	1.80	1.827	
			-40°C to +85°C	1.710		1.899	
				1.906			
Throobold voltage	$V_{TH}$	EM6325 – 2.2	+25°C	2.167	2.20	2.233	V
Threshold voltage (note 3)			-40°C to +85°C	2.090		2.321	
(note 3)			-40°C to +125°C	2.050		2.330	
		EM6325 - 2.6	+25°C	2.591	2.63	2.669	
			-40°C to +85°C	2.499		2.775	
			-40°C to +125°C	2.451		2.785	
			+25°C	2.886	2.93	2.974	
		EM6325 - 2.9	-40°C to +85°C	2.784		3.091	
			-40°C to +125°C	2.731		3.103	
			+25°C	3.034	3.08	3.126	
		EM6325 - 3.1	-40°C to +85°C	2.926		3.249	
			-40°C to +125°C	2.871		3.262	1
		EM6325 – 4.4	+25°C	4.334		4.466	
			-40°C to +85°C	4.180	4.40	4.642	
			-40°C to +125°C	4.101		4.660	
		EM6325 – 4.6	+25°C	4.561		4.699	
			-40°C to +85°C	4.399	4.63	4.885	
			-40°C to +125°C	4.315	1	4.903	
Threshold hysteresis	$V_{HYS}$	T <sub>A</sub> =	=+25°C	-	2.1%•V <sub>TH</sub>	-	V

**Note 1:** Production tested at +25°C only. Over temperature limits are guaranteed by design, not production tested.

Note 3: Threshold voltage is specified for V<sub>DD</sub> falling.



#### **Electrical Characteristics** (continued)

Unless otherwise specified:  $V_{DD}$ = 0.9V to 5.5V,  $T_A$ =-40°C to +125° C (note 1).

Parameter	Symbol	Conditions		Min	Тур	Max	Unit	
		(note 2 and 4) EM63:		EM6325C	155	200	224	- ms
Reset timeout period	t <sub>POR</sub>			EM6325A	0.7	1.6	3.8	
Reset timeout period	<b>₽</b> POR			EM6325B	19.4	25	28	
			EM6325D		1240	1600	1792	
Propagation delay time V <sub>DD</sub> to RESET (RESET) delay	t <sub>P</sub>	$V_{DD}$ drops from $V_{TH (t)}$ (note 2). $T_A$ = +25°C	<sub>yp)</sub> +0.2V to \	V <sub>TH (typ)</sub> -0.2V	2	130	255	μS
		V <sub>DD</sub> >1V	I <sub>OL</sub> =100μA		-	-	0.3	V
Open-drain RESET output	$V_{OL}$	V <sub>DD</sub> >2.5V	I <sub>OL</sub> =1.5mA		-	-	0.3	
Voltage		V <sub>DD</sub> >5V	I <sub>OL</sub> =3mA		-	-	0.35	
	V <sub>OL</sub>	V <sub>DD</sub> >1V	I <sub>OL</sub> =100μA		-	-	0.3	V
		V <sub>DD</sub> >2.5V	I <sub>OL</sub> =1.5mA		-	-	0.3	
Push-pull RESET / RESET		V <sub>DD</sub> >5V	I <sub>OL</sub> =3mA		-	-	0.35	
Output voltage	V <sub>OH</sub>	V <sub>DD</sub> >1V	I <sub>OH</sub> =-30μA		0.8	-	-	
		V <sub>DD</sub> >2.5V	I <sub>OH</sub> =-1.5mA 2		2	-	-	
		V <sub>DD</sub> >5V	I <sub>OH</sub> =-3mA		4	-	-	
Output leakage current	tput leakage current I <sub>LEAK</sub> Only for EM6325_Y (open-drain)			-	-	0.5	μΑ	
MANUAL RESET (MR)								
MR Input low	V <sub>MRT</sub> low						0.3•V <sub>DD</sub>	V
MR Input high	V <sub>MRT</sub> high	T <sub>A</sub> = +25°C		0.7•V <sub>DD</sub>			V	
MR to Reset delay	t <sub>MD</sub>				0.3		μS	
Pulse width at MR (note 5)	t <sub>PMD</sub>			1			μS	
MR Internal Pull-up resistor	$R_{MR}$	T <sub>A</sub> =-40°C to +125°C		4.8	15	31	kΩ	

**Note 1:** Production tested at +25°C only. Over temperature limits are guaranteed by design, not production tested.

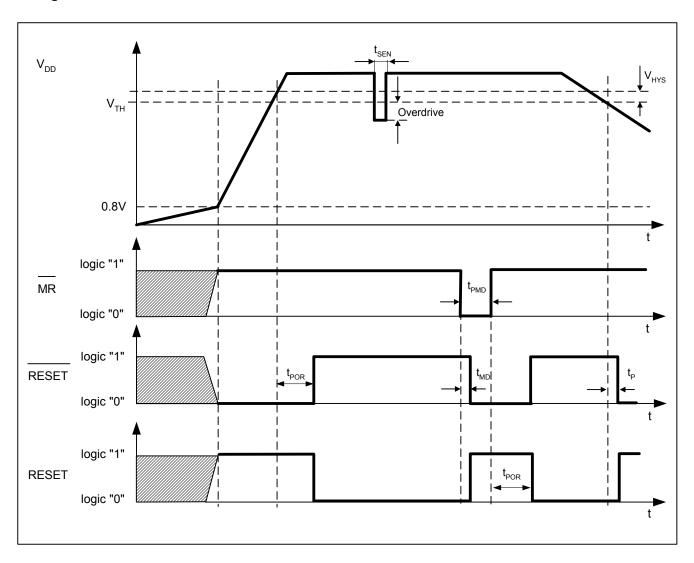
Note 2: RESET (RESET) open.

**Note 4:** Standard version for t<sub>POR</sub> is 200ms (typ), available at all times. Other option (1.6ms, 25ms, 1600ms) are available by mask option and upon minimum order quantity. Please contact EM sales.

Note 5: Pulse width must be greater than  $1\mu s$  to ensure the  $\overline{\text{RESET}}$  (RESET) to go active.



### **Timing Waveforms**



**Note 6:** t<sub>SEN</sub> = Maximum Transient Duration. Please refer to figure on the next page.

**Note 7:** Overdrive =  $V_{TH}$  - $V_{DD}$ . Please refer to figure on the next page.

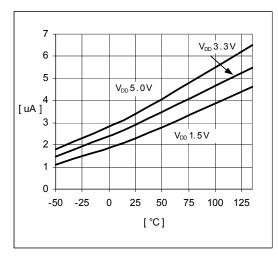
### **Manual Reset Input**

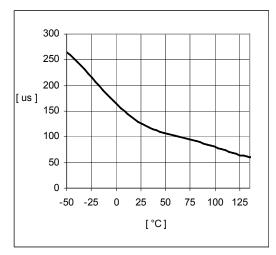
A logic low on  $\overline{\text{MR}}$  asserts a reset. Reset remains asserted while  $\overline{\text{MR}}$  is low, and for  $t_{POR}$  (200ms nominal for EM6325C) after it returns high.  $\overline{\text{MR}}$  has an internal 15k $\Omega$  pull-up resistor, so it can be left open if unused. This input can be driven with CMOS logic levels or with open-drain outputs. Connect a normally open momentary switch from  $\overline{\text{MR}}$  to  $V_{SS}$  to create a manual-reset function; debounce circuitry is integrated. If  $\overline{\text{MR}}$  is driven from long cable or the device is used in a noisy environment, connect a  $0.1\mu\text{F}$  capacitor from  $\overline{\text{MR}}$  to  $V_{SS}$  to provide additional noise immunity (stronger external additional pull-up resistor can also be added).



### **Typical Operating Characteristics**

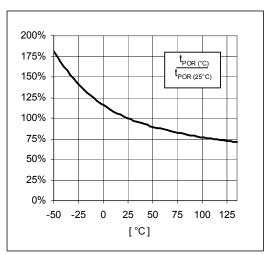
(Typical values are at  $T_A$ =+25°C unless otherwise noted,  $\overline{MR}$ ,  $\overline{RESET}$  and  $\overline{RESET}$  open.)

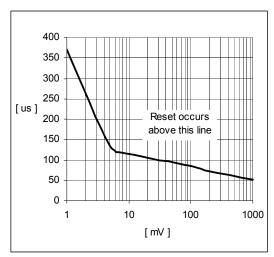




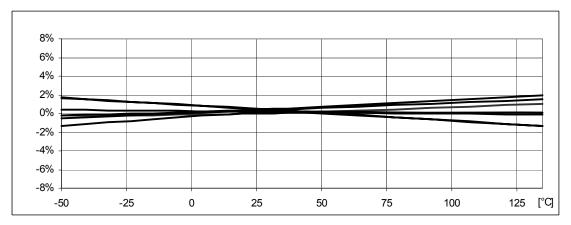
I<sub>DD</sub> vs. Temperature

Propagation Time t<sub>P</sub> vs. Temperature





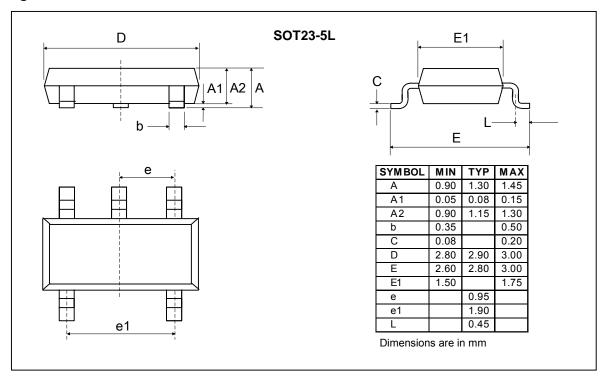
Reset Timeout Period  $t_{POR}$  vs. Temperature (normalized with respect to  $t_{POR\ 25^{\circ}C}$ )

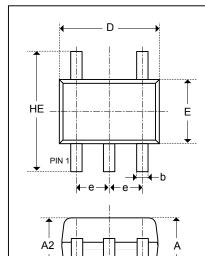


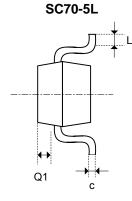
Threshold Voltage Variation vs. Temperature (normalized)



# **Package Information**





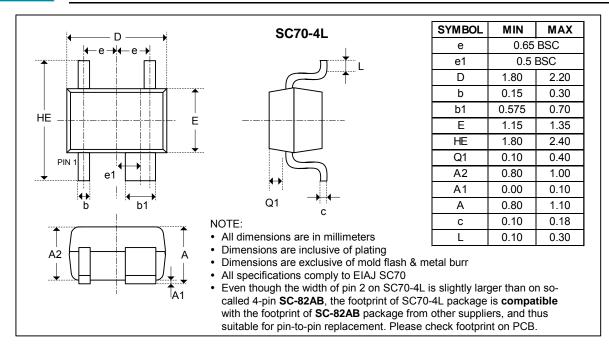


SYMBOL	MIN	MAX		
е	0.65 BSC			
D	1.80	2.20		
b	0.15	0.30		
Е	1.15	1.35		
HE	1.80	2.40		
Q1	0.10	0.40		
A2	0.80	1.00		
A1	0.00	0.10		
Α	0.80	1.10		
С	0.10	0.18		
L	0.10	0.30		

#### NOTE:

- All dimensions are in millimeters
- Dimensions are inclusive of plating
- Dimensions are exclusive of mold flash & metal burr All specifications comply to EIAJ SC70





#### Traceability for small packages

Due to the limited space on the package surface, the bottom marking contains a limited number of characters that provide only partial information for lot traceability. Full information for complete traceability is however provided on the packing labels of the product at delivery from EM. It is highly recommended that the customer insures full lot traceability of EM product in his final product.

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